

70V3579S4DR

70V3579S4DR Information

www.heisener.com	Part Number Manufacturer Category Description Package	70V3579S4DR IDT, Integrated Device Technology Inc Integrated Circuits (ICs) Memory IC SRAM 1.125MBIT 4.2NS 208QFP 208-BFQFP For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



70V3579S4DR Specifications

Manufacturer Part Number	70V3579S4DR
Manufacturer	IDT, Integrated Device Technology Inc
Category	Integrated Circuits (ICs)
	Memory
Package	208-BFQFP
Series	-
Memory Type	Volatile
Memory Format	SRAM
Technology	SRAM - Dual Port, Synchronous
Memory Size	1.125Mb (32K x 36)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	-
Access Time	4.2ns
Voltage - Supply	3.15 V ~ 3.45 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
	Report errors?

70V3579S4DR Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE UARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

70V3579S4DR Payment Methods





If you have any question about 70V3579S4DR, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com